NSN 5962-01-026-0495

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.735 inches and 0.830 inches

Body Width:

Between 0.245 inches and 0.295 inches

Body Height:

0.160 inches

Maximum Power Dissipation Rating:

512.0 milliwatts

Operating Tempurature Range:

-65.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+160.0 degrees celsius

Features Provided:

Hermetically sealed and expandable and programmable and schottky and bipolar and high speed and w/open collector

Inclosure Material:

Ceramic and metal

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.0 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

70.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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